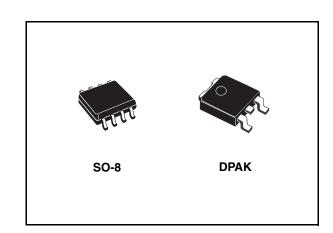


#### Very low drop voltage regulators with inhibit

#### **Features**

- Very low dropout voltage (0.4 V)
- Very low quiescent current (typ. 50 μA in OFF mode, 500 μA in ON mode)
- Output current up to 500 mA
- Logic-controlled electronic shutdown
- Output voltages of 1.5; 2.5; 3.3; 4; 5; 8 V
- Internal current and thermal limit
- Only 2.2 µF for stability
- Available in ± 2 % accuracy at 25 °C
- Supply voltage rejection: 70 db (typ.)
- Temperature range: -40 to 125 °C



#### **Description**

The KFxx series are very low drop regulators available in SO-8 package and in a wide range of output voltages.

The very low drop voltage (0.4 V) and the very low quiescent current make them particularly

suitable for low noise, low power applications and specially in battery powered systems.

A shutdown logic control function is available (pin 5, TTL compatible). This means that when the device is used as a local regulator, it is possible to put a part of the board in standby, decreasing the total power consumption. It requires only a 2.2  $\mu$ F capacitor for stability allowing space and cost saving.

Table 1. Device summary

Part numbers					
KF15B	KF40B				
KF25B	KF50B				
KF33B	KF80B				

Contents KFxxB

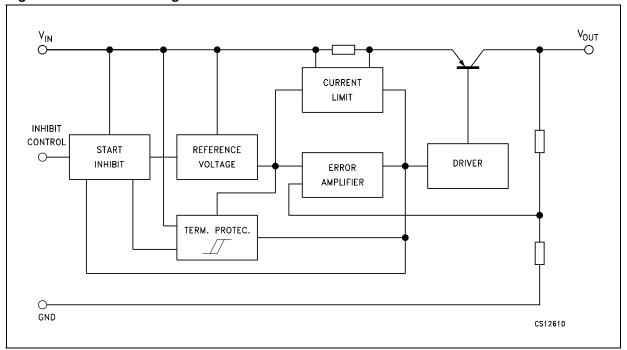
### **Contents**

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5	Typical performance characteristics
6	Package mechanical data
7	Order codes
8	Revision history

KFxxB Diagram

# 1 Diagram

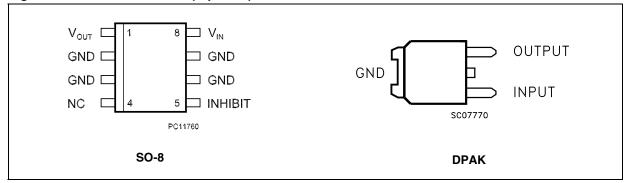
Figure 1. Schematic diagram



Pin configuration KFxxB

# 2 Pin configuration

Figure 2. Pin connections (top view)



KFxxB Maximum ratings

## 3 Maximum ratings

Table 2. Absolute maximum ratings

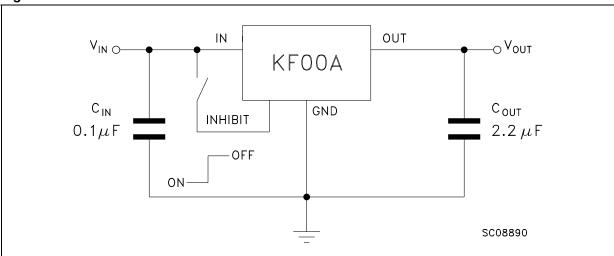
Symbol	Parameter	Value	Unit
VI	DC input voltage	-0.5 to 20	V
I <sub>O</sub>	Output current	Internally Limited	
P <sub>TOT</sub>	Power dissipation	Internally Limited	
T <sub>STG</sub>	Storage temperature range	ange -40 to 150	
T <sub>OP</sub>	Operating junction temperature range	-40 to 125	°C

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Table 3. Thermal data

Symbol	Parameter	DPAK	SO-8	Unit
R <sub>thJC</sub>	Thermal resistance junction-case	8	20	°C/W

Figure 3. Test circuit



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Electrical characteristics KFxxB

### 4 Electrical characteristics

Table 4. Electrical characteristics for KF15 (refer to the test circuits,  $T_J$  = 25 °C,  $C_I$  = 0.1 μF,  $C_O$  = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	s	Min.	Тур.	Max.	Unit
V	Output voltage	I <sub>O</sub> = 50 mA, V <sub>I</sub> = 3.5 V		1.47	1.5	1.53	V
Vo	Output voltage	$I_O = 50 \text{ mA}, V_I = 3.5 \text{ V}, T_a =$	$I_O = 50 \text{ mA}, V_I = 3.5 \text{ V}, T_a = -25 \text{ to } 85^{\circ}\text{C}$			1.56	V
VI	Operating input voltage	I <sub>O</sub> = 500 mA		2.5		20	V
I <sub>O</sub>	Output current limit				1		Α
$\Delta V_{O}$	Line regulation	$V_1 = 2.5 \text{ to } 20 \text{ V}, I_0 = 5 \text{ mA}$			2	12	mV
$\Delta V_{O}$	Load regulation	$V_I = 2.8 \text{ V}, I_O = 5 \text{ to } 500 \text{ mA}$	,		2	50	mV
		$V_1 = 2.5 \text{ to } 20V, I_0 = 0\text{mA}$	ON MODE		0.5	1	mA
I <sub>d</sub>	Quiescent current	$V_{I} = 2.8 \text{ to } 20V, I_{O} = 500 \text{mA}$				12	mA
		V <sub>I</sub> = 6 V	OFF MODE		50	100	μΑ
			f = 120 Hz		82		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 3.5 \pm 1 \text{ V}$	f = 1 kHz		77		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 kHz			50		μV
V <sub>d</sub>	Dropout voltage	I <sub>O</sub> = 200 mA			1		V
V <sub>IL</sub>	Control input logic low	T <sub>a</sub> = -40 to 125°C				0.8	V
V <sub>IH</sub>	Control input logic high	T <sub>a</sub> = -40 to 125°C		2			V
I <sub>I</sub>	Control input current	V <sub>I</sub> = 6 V, V <sub>C</sub> = 6 V			10		μΑ
Co	Output bypass capacitance	ESR = 0.1 to 10 $\Omega$ , $I_O$ = 0 to	500 mA	2	10		μF

Table 5. Electrical characteristics for KF25 (refer to the test circuits,  $T_J$  = 25 °C,  $C_I$  = 0.1 μF,  $C_O$  = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit
V	Output voltage	I <sub>O</sub> = 50 mA, V <sub>I</sub> = 4.5 V		2.45	2.5	2.55	V
Vo	Output voltage	$I_O = 50 \text{ mA}, V_I = 4.5 \text{ V}, T_a =$	$I_O = 50 \text{ mA}, V_I = 4.5 \text{ V}, T_a = -25 \text{ to } 85^{\circ}\text{C}$			2.6	V
VI	Operating input voltage	I <sub>O</sub> = 500 mA				20	V
Io	Output current limit				1		Α
$\Delta V_{O}$	Line regulation	$V_1 = 3.5 \text{ to } 20 \text{ V}, I_0 = 5 \text{ mA}$			2	12	mV
$\Delta V_{O}$	Load regulation	$V_1 = 3.8 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	1		2	50	mV
		$V_1 = 3.5 \text{ to } 20V, I_0 = 0\text{mA}$	ONLMODE		0.5	1	4
$I_d$	Quiescent current	$V_1 = 3.8 \text{ to } 20V, I_0 = 500\text{mA}$	ON MODE			12	mA
		V <sub>I</sub> = 6 V	OFF MODE		50	100	μA
			f = 120 Hz		82		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 4.5 \pm 1 \text{ V}$	f = 1 kHz		77		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz	1		50		μV
M	Donostock	I <sub>O</sub> = 200 mA			0.2	0.35	.,
$V_d$	Dropout voltage I <sub>O</sub> = 500 mA		0.4	0.7	V		
V <sub>IL</sub>	Control input logic low	T <sub>a</sub> = -40 to 125°C				0.8	٧
V <sub>IH</sub>	Control input logic high	T <sub>a</sub> = -40 to 125°C	T <sub>a</sub> = -40 to 125°C				V
I <sub>I</sub>	Control input current	V <sub>I</sub> = 6 V, V <sub>C</sub> = 6 V			10		μA
C <sub>O</sub>	Output bypass capacitance	ESR = 0.1 to 10 $\Omega$ , $I_0 = 0$ to	500 mA	2	10		μF

Electrical characteristics KFxxB

Table 6. Electrical characteristics for KF33 (refer to the test circuits,  $T_J$  = 25 °C,  $C_I$  = 0.1 μF,  $C_O$  = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit
V.	Output voltage	$I_O = 50 \text{ mA}, V_I = 5.3 \text{ V}$		3.234	3.3	3.366	V
V <sub>O</sub>	Output voltage	$I_O = 50 \text{ mA}, V_I = 5.3 \text{ V}, T_a =$	$I_O = 50 \text{ mA}, V_I = 5.3 \text{ V}, T_a = -25 \text{ to } 85^{\circ}\text{C}$			3.432	V
V <sub>I</sub>	Operating input voltage	I <sub>O</sub> = 500 mA				20	V
I <sub>O</sub>	Output current limit				1		Α
$\Delta V_{O}$	Line regulation	$V_1 = 4.3 \text{ to } 20 \text{ V}, I_0 = 5 \text{ mA}$			2	12	mV
$\Delta V_{O}$	Load regulation	$V_1 = 4.6 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	1		2	50	mV
		$V_1 = 4.3 \text{ to } 20V, I_0 = 0\text{mA}$	ONLMODE		0.5	1	A
$I_d$	Quiescent current	V <sub>I</sub> = 4.6 to 20V, I <sub>O</sub> =500mA	ON MODE			12	mA
		V <sub>I</sub> = 6 V	OFF MODE		50	100	μA
			f = 120 Hz		80		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 5.3 \pm 1 \text{ V}$	f = 1 kHz		75		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz	•		50		μV
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	D	I <sub>O</sub> = 200 mA			0.2	0.35	.,
$V_d$	Dropout voltage I <sub>O</sub> = 500 mA		0.4	0.7	V		
V <sub>IL</sub>	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	V
V <sub>IH</sub>	Control input logic high	T <sub>a</sub> = -40 to 125°C					V
I <sub>I</sub>	Control input current	V <sub>I</sub> = 6 V, V <sub>C</sub> = 6 V			10		μA
Co	Output bypass capacitance	ESR = 0.1 to 10 $\Omega$ , $I_0 = 0$ to	500 mA	2	10		μF

Table 7. Electrical characteristics for KF40 (refer to the test circuits,  $T_J = 25$  °C,  $C_I = 0.1$  μF,  $C_O = 2.2$  μF unless otherwise specified.)

Symbol	Parameter	Test condition	s	Min.	Тур.	Max.	Unit
V	Output voltage	I <sub>O</sub> = 50 mA, V <sub>I</sub> = 6 V		3.92	4	4.08	V
Vo	Output voltage	$I_O = 50 \text{ mA}, V_I = 6 \text{ V}, T_a = -6 \text{ V}$	$I_O = 50 \text{ mA}, V_I = 6 \text{ V}, T_a = -25 \text{ to } 85^{\circ}\text{C}$			4.16	V
VI	Operating input voltage	I <sub>O</sub> = 500 mA				20	V
Io	Output current limit				1		Α
$\Delta V_{O}$	Line regulation	$V_1 = 5 \text{ to } 20 \text{ V}, I_0 = 5 \text{ mA}$			3	18	mV
$\Delta V_{O}$	Load regulation	$V_1 = 5.3 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	i		2	50	mV
		$V_1 = 5 \text{ to } 20V, I_0 = 0mA$	ON MODE		0.5	1	Л
I <sub>d</sub>	Quiescent current	$V_I = 5.3 \text{ to } 20\text{V}, I_O = 500\text{mA}$ ON MODE $V_I = 6 \text{ V}$ OFF MODE	ON MODE			12	mA
			V <sub>I</sub> = 6 V OFF MODE		50	100	μΑ
			f = 120 Hz		78		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 6 \pm 1 \text{ V}$	f = 1 kHz		73		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz	•		50		μV
.,	Duranturaltana	I <sub>O</sub> = 200 mA			0.2	0.35	\ <i>I</i>
V <sub>d</sub>	Oropout voltage I <sub>O</sub> = 500 mA		0.4	0.7	V		
V <sub>IL</sub>	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	٧
V <sub>IH</sub>	Control input logic high	$T_a = -40 \text{ to } 125^{\circ}\text{C}$	T <sub>a</sub> = -40 to 125°C				V
I <sub>I</sub>	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$			10		μΑ
Co	Output bypass capacitance	ESR = 0.1 to 10 Ω, $I_0$ = 0 to	500 mA	2	10		μF

Electrical characteristics KFxxB

Table 8. Electrical characteristics for KF50 (refer to the test circuits,  $T_J$  = 25 °C,  $C_I$  = 0.1 μF,  $C_O$  = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit
V	Output voltage	I <sub>O</sub> = 50 mA, V <sub>I</sub> = 7 V	$I_{O} = 50 \text{ mA}, V_{I} = 7 \text{ V}$		5	5.1	V
V <sub>O</sub>	Output voltage	$I_O = 50 \text{ mA}, V_I = 7 \text{ V}, T_a = -100 \text{ mA}$	$I_O = 50 \text{ mA}, V_I = 7 \text{ V}, T_a = -25 \text{ to } 85^{\circ}\text{C}$			5.2	v
V <sub>I</sub>	Operating input voltage	I <sub>O</sub> = 500 mA				20	V
Io	Output current limit				1		Α
$\Delta V_{O}$	Line regulation	V <sub>I</sub> = 6 to 20 V, I <sub>O</sub> = 5 mA			3	18	mV
$\Delta V_{O}$	Load regulation	$V_1 = 6.3 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	1		2	50	mV
		V <sub>I</sub> = 6 to 20V, I <sub>O</sub> = 0mA	ON MODE		0.5	1	Л
$I_{d}$	Quiescent current	$V_1 = 6.3 \text{ to } 20V, I_0 = 500 \text{mA}$	ON MODE			12	mA
		V <sub>I</sub> = 6 V	V <sub>I</sub> = 6 V OFF MODE		50	100	μΑ
			f = 120 Hz		76		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 7 \pm 1 \text{ V}$	f = 1 kHz		71		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz			50		μV
M	Dranautwaltana	I <sub>O</sub> = 200 mA			0.2	0.35	.,
$V_d$	Dropout voltage I <sub>O</sub> = 500 mA		0.4	0.7	V		
$V_{IL}$	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	V
V <sub>IH</sub>	Control input logic high	T <sub>a</sub> = -40 to 125°C	T <sub>a</sub> = -40 to 125°C				V
I <sub>I</sub>	Control input current	V <sub>I</sub> = 6 V, V <sub>C</sub> = 6 V			10		μΑ
Co	Output bypass capacitance	ESR = 0.1 to 10 $\Omega$ I <sub>O</sub> = 0 to	500 mA	2	10		μF

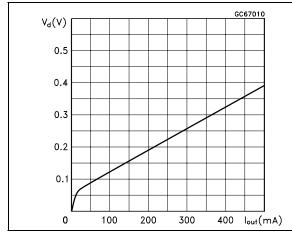
Table 9. Electrical characteristics for KF80 (refer to the test circuits,  $T_J$  = 25 °C,  $C_I$  = 0.1 μF,  $C_O$  = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit
V.	Output voltage	I <sub>O</sub> = 50 mA, V <sub>I</sub> = 10 V	$I_{O} = 50 \text{ mA}, V_{I} = 10 \text{ V}$		8	8.16	V
V <sub>O</sub>	Jaipai Vollago	$I_O = 50 \text{ mA}, V_I = 10 \text{ V}, T_a =$	-25 to 85°C	7.68		8.32	v
VI	Operating input voltage	I <sub>O</sub> = 500 mA				20	٧
I <sub>O</sub>	Output current limit				1		Α
ΔV <sub>O</sub>	Line regulation	V <sub>I</sub> = 9 to 20 V, I <sub>O</sub> = 5 mA			4	24	mV
$\Delta V_{O}$	Load regulation	$V_{I} = 9.3 \text{ V}, I_{O} = 5 \text{ to } 500 \text{ mA}$	Ĺ		2	50	mV
		$V_{I} = 9 \text{ to } 20V, I_{O} = 0\text{mA}$	ON MODE		0.7	1.5	А
I <sub>d</sub>	Quiescent current		$V_1 = 9.3 \text{ to } 20V, I_0 = 500 \text{mA}$			12	mA
		V <sub>I</sub> = 9 V OFF MODE	V <sub>I</sub> = 9 V OFF MODE		70	140	μΑ
			f = 120 Hz		72		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 10 \pm 1 \text{ V}$	f = 1 kHz		67		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz	•		50		μV
	Dunantualtana	I <sub>O</sub> = 200 mA			0.2	0.35	.,
$V_d$	Dropout voltage	I <sub>O</sub> = 500 mA			0.4	0.7	V
V <sub>IL</sub>	Control input logic low	T <sub>a</sub> = -40 to 125°C				0.8	٧
V <sub>IH</sub>	Control input logic high	T <sub>a</sub> = -40 to 125°C		2			٧
I <sub>I</sub>	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$			10		μΑ
Co	Output bypass capacitance	ESR = 0.1 to 10 $\Omega$ , $I_0 = 0$ to	500 mA	2	10		μF

## 5 Typical performance characteristics

(unless otherwise specified  $V_{O(NOM)} = 3.3 \text{ V}$ )

Figure 4. Dropout voltage vs output current Figure 5. Dropout voltage vs temperature



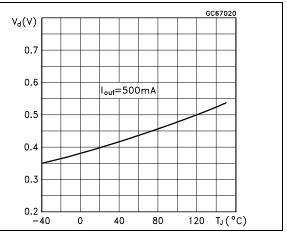


Figure 6. Supply current vs input voltage

16 | I<sub>out</sub>=500mA | 12 | 8 | 4 | 0 | 0 | 4 | 8 | 12 | 16 | V<sub>i</sub>(V)

Figure 7. Supply current vs input voltage

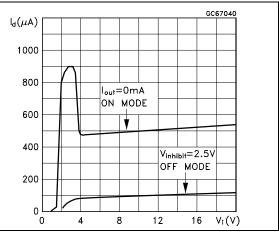
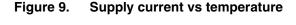
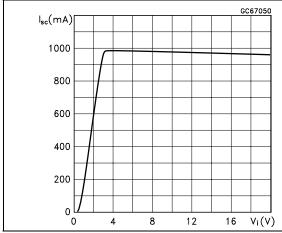
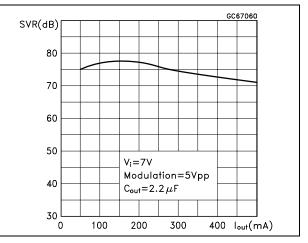


Figure 8. Short circuit current vs input voltage







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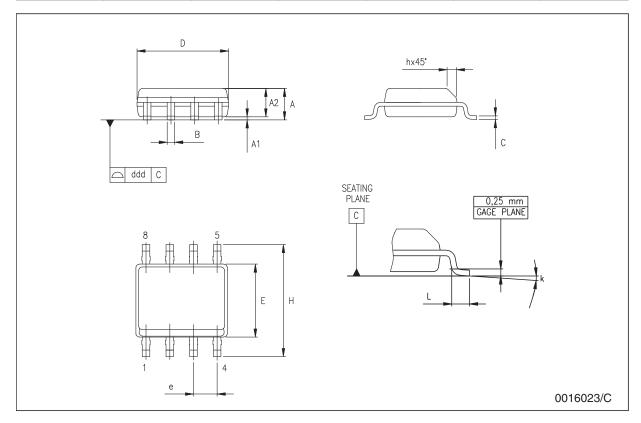
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### 6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

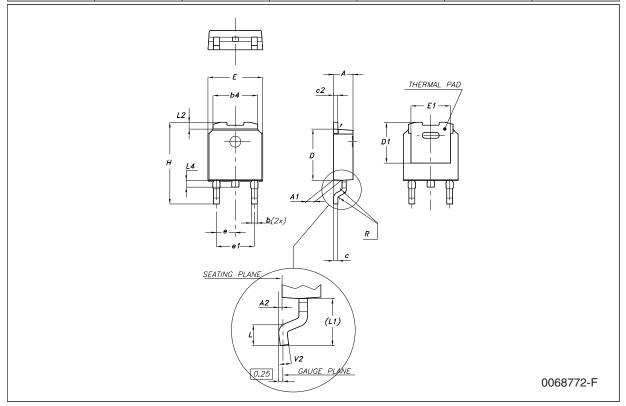
#### SO-8 mechanical data

Dim.		mm.			inch.	
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.
А	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
е		1.27			0.050	
Н	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k			8° (n	nax.)	•	
ddd			0.1			0.04



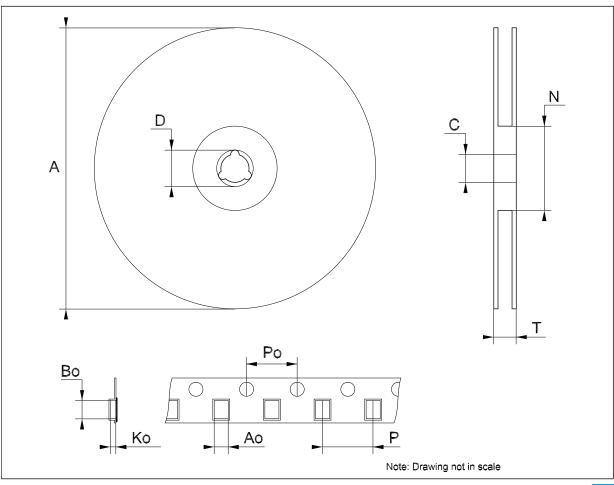
#### **DPAK** mechanical data

Dim		mm.				
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A2	0.03		0.23	0.001		0.009
В	0.64		0.9	0.025		0.035
b4	5.2		5.4	0.204		0.212
С	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
D1		5.1			0.200	
Е	6.4		6.6	0.252		0.260
E1		4.7			0.185	
е		2.28			0.090	
e1	4.4		4.6	0.173		0.181
Н	9.35		10.1	0.368		0.397
L	1			0.039		
(L1)		2.8			0.110	
L2		0.8			0.031	
L4	0.6		1	0.023		0.039
R		0.2			0.008	
V2	0°		8°	0°		8°



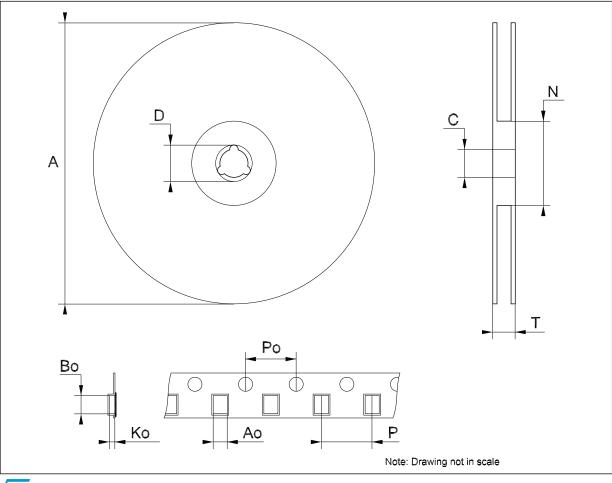
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Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



	_	_					
Tana	Ω.	rool		K_DD	NK	mechanical	data
Iabe	CX.	ICCI	$\nu$ $\Gamma$ $\Lambda$	11 <b>7</b> -L	$\Delta$ I	IIICCHailicai	uata

Dim.		mm.		inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.80	6.90	7.00	0.268	0.272	0.2.76
Во	10.40	10.50	10.60	0.409	0.413	0.417
Ko	2.55	2.65	2.75	0.100	0.104	0.105
Po	3.9	4.0	4.1	0.153	0.157	0.161
Р	7.9	8.0	8.1	0.311	0.315	0.319



Order codes KFxxB

### 7 Order codes

Table 10. Order codes

Pac	Output voltage		
SO-8 (tape and reel)	DPAK (tape and reel)	Output voltage	
	KF15BDT-TR	1.5 V	
KF25BD-TR	KF25BDT-TR	2.5 V	
KF33BD-TR	KF33BDT-TR	3.3 V	
	KF40BDT-TR	4 V	
KF50BD-TR	KF50BDT-TR	5 V	
	KF80BDT-TR	8 V	

KFxxB Revision history

# 8 Revision history

Table 11. Document revision history

Date	Revision	Changes
06-Jun-2007	9	Order codes updated.
14-Dec-2007	10	Modified: Table 10.
21-Feb-2008	11	Modified: Table 10 on page 18.

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